

## N-Channel Power MOSFET

40V, 44A, 11mΩ

### FEATURES

- Low  $R_{DS(ON)}$  to minimize conductive losses
- Logic level
- Low gate charge for fast power switching
- 100% UIS and  $R_g$  Tested
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

### KEY PERFORMANCE PARAMETERS

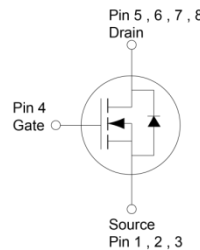
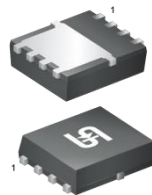
PARAMETER	VALUE	UNIT
$V_{DS}$	40	V
$R_{DS(on)}$ (max)	$V_{GS} = 10V$	11
	$V_{GS} = 4.5V$	16
$Q_g$	12	nC

### APPLICATIONS

- BLDC Motor Control
- Battery Power Management
- DC-DC Converter
- Secondary Synchronous Rectification



PDFN33



Note: MSL 1 (Moisture Sensitivity Level) per J-STD-020

### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT
Drain-Source Voltage	$V_{DS}$	40	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current (Note 1)	$I_D$	$T_C = 25^\circ\text{C}$	44
		$T_A = 25^\circ\text{C}$	9
Pulsed Drain Current	$I_{DM}$	176	A
Single Pulse Avalanche Current (Note 2)	$I_{AS}$	14	A
Single Pulse Avalanche Energy (Note 2)	$E_{AS}$	29	mJ
Total Power Dissipation	$P_D$	$T_C = 25^\circ\text{C}$	42
		$T_C = 125^\circ\text{C}$	8
Total Power Dissipation	$P_D$	$T_A = 25^\circ\text{C}$	1.9
		$T_A = 125^\circ\text{C}$	0.4
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	- 55 to +150	$^\circ\text{C}$

### THERMAL PERFORMANCE

PARAMETER	SYMBOL	MAXIMUM	UNIT
Junction to Case Thermal Resistance	$R_{\theta JC}$	3	$^\circ\text{C/W}$
Junction to Ambient Thermal Resistance	$R_{\theta JA}$	65	$^\circ\text{C/W}$

**Thermal Performance Note:**  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design. The  $R_{\theta JA}$  limit presented here is based on mounting on a 1 in<sup>2</sup> pad of 2 oz copper.

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_A = 25^\circ\text{C}$ unless otherwise noted)						
<b>PARAMETER</b>	<b>CONDITIONS</b>	<b>SYMBOL</b>	<b>MIN</b>	<b>TYP</b>	<b>MAX</b>	<b>UNIT</b>
<b>Static</b>						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	$BV_{DSS}$	40	--	--	V
Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250\mu A$	$V_{GS(TH)}$	1	1.7	2.5	V
Gate-Source Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$	$I_{GSS}$	--	--	$\pm 100$	nA
Drain-Source Leakage Current	$V_{GS} = 0V, V_{DS} = 40V$	$I_{DSS}$	--	--	1	$\mu A$
	$V_{GS} = 0V, V_{DS} = 40V$ $T_J = 125^\circ\text{C}$		--	--	100	
Drain-Source On-State Resistance (Note 3)	$V_{GS} = 10V, I_D = 9A$	$R_{DS(on)}$	--	7	11	m $\Omega$
	$V_{GS} = 4.5V, I_D = 8A$		--	10	16	
Forward Transconductance (Note 3)	$V_{DS} = 10V, I_D = 9A$	$g_{fs}$	--	35	--	S
<b>Dynamic</b> (Note 4)						
Total Gate Charge	$V_{GS} = 10V, V_{DS} = 20V,$ $I_D = 9A$	$Q_g$	--	24	--	nC
Total Gate Charge	$V_{GS} = 4.5V, V_{DS} = 20V,$ $I_D = 8A$	$Q_g$	--	12	--	
Gate-Source Charge		$Q_{gs}$	--	4	--	
Gate-Drain Charge		$Q_{gd}$	--	6	--	
Input Capacitance	$V_{GS} = 0V, V_{DS} = 20V,$ $f = 1.0\text{MHz}$	$C_{iss}$	--	1329	--	pF
Output Capacitance		$C_{oss}$	--	147	--	
Reverse Transfer Capacitance		$C_{rss}$	--	82	--	
Gate Resistance	$f = 1.0\text{MHz}$	$R_g$	0.7	2.3	4.6	$\Omega$
<b>Switching</b> (Note 4)						
Turn-On Delay Time	$V_{GS} = 10V, V_{DS} = 20V,$ $I_D = 9A, R_G = 2\Omega$	$t_{d(on)}$	--	3	--	ns
Turn-On Rise Time		$t_r$	--	23	--	
Turn-Off Delay Time		$t_{d(off)}$	--	16	--	
Turn-Off Fall Time		$t_f$	--	20	--	
<b>Source-Drain Diode</b>						
Forward Voltage (Note 3)	$V_{GS} = 0V, I_S = 9A$	$V_{SD}$	--	--	1.2	V
Reverse Recovery Time	$I_S = 9A,$ $di/dt = 100A/\mu s$	$t_{rr}$	--	14	--	ns
Reverse Recovery Charge		$Q_{rr}$	--	7	--	nC

**Notes:**

1. Silicon limited current only.
2.  $L = 0.3\text{mH}, V_{GS} = 10V, V_{DD} = 30V, R_G = 25\Omega, I_{AS} = 14A,$  Starting  $T_J = 25^\circ\text{C}$
3. Pulse test: Pulse Width  $\leq 300\mu s,$  duty cycle  $\leq 2\%$ .
4. Switching time is essentially independent of operating temperature.

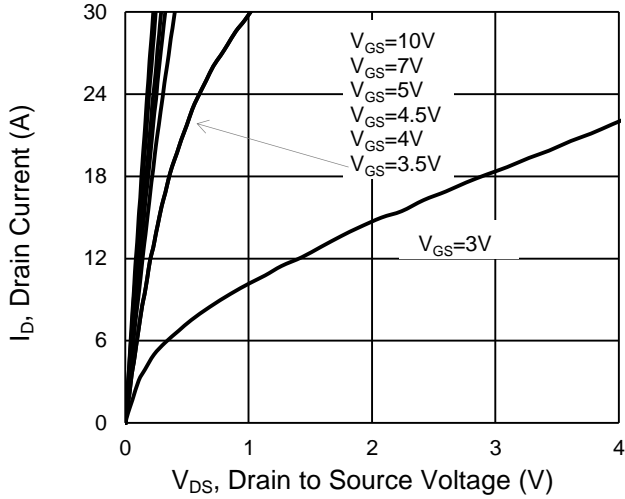
**ORDERING INFORMATION**

<b>ORDERING CODE</b>	<b>PACKAGE</b>	<b>PACKING</b>
TSM110NB04LCV RGG	PDFN33	5,000pcs / 13" Reel

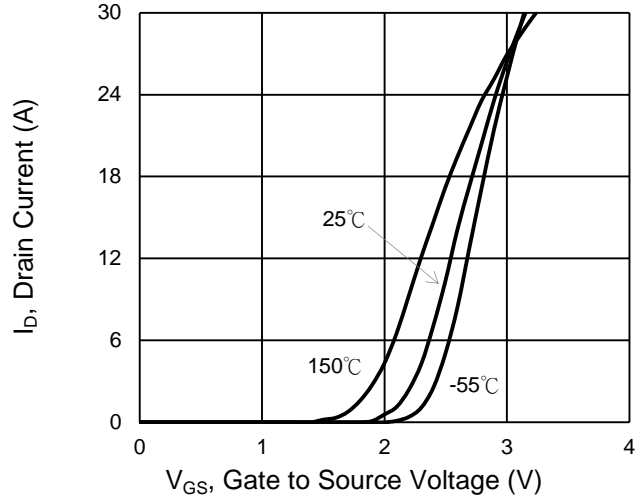
**CHARACTERISTICS CURVES**

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

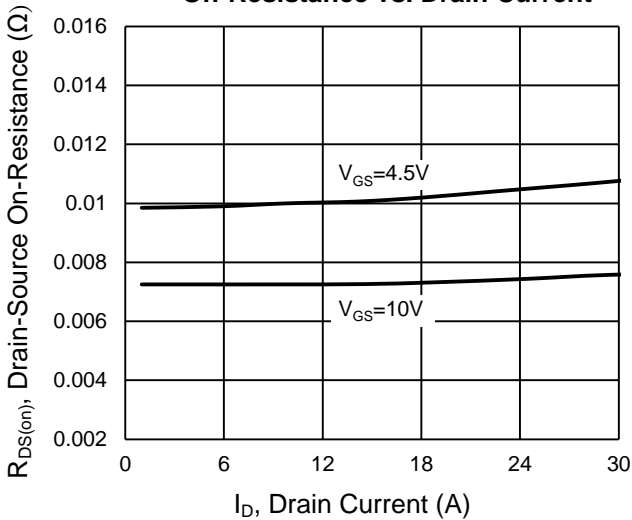
**Output Characteristics**



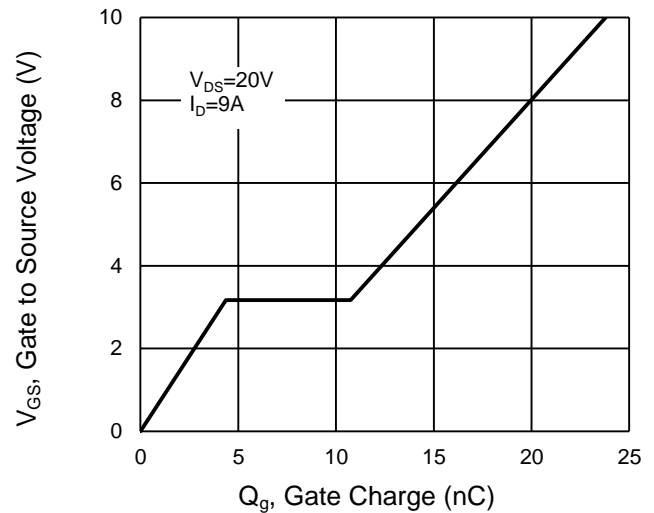
**Transfer Characteristics**



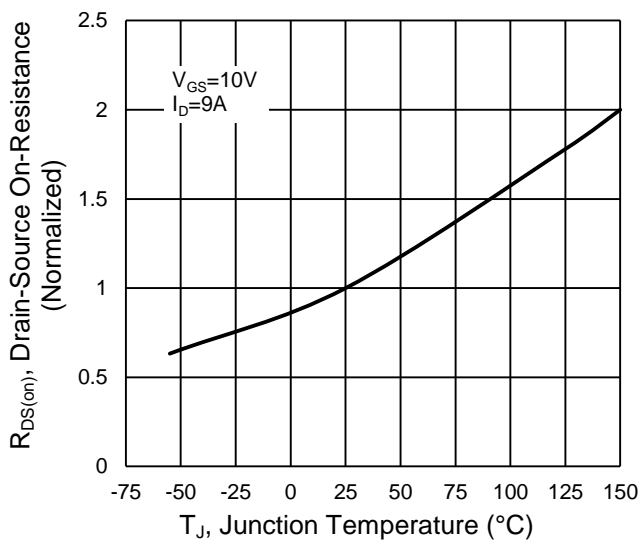
**On-Resistance vs. Drain Current**



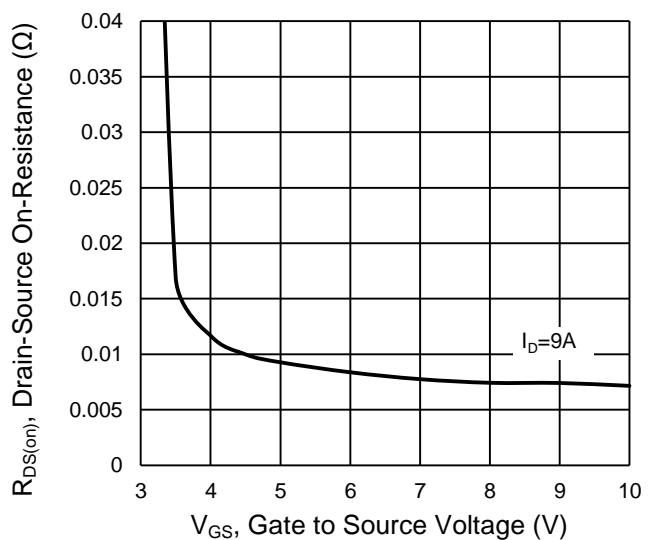
**Gate-Source Voltage vs. Gate Charge**



**On-Resistance vs. Junction Temperature**

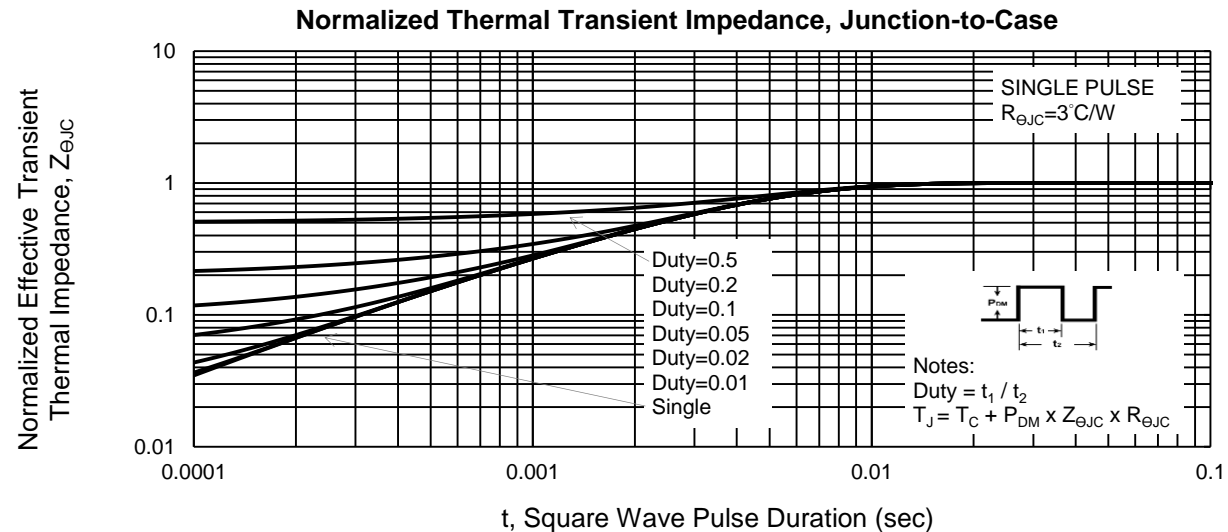
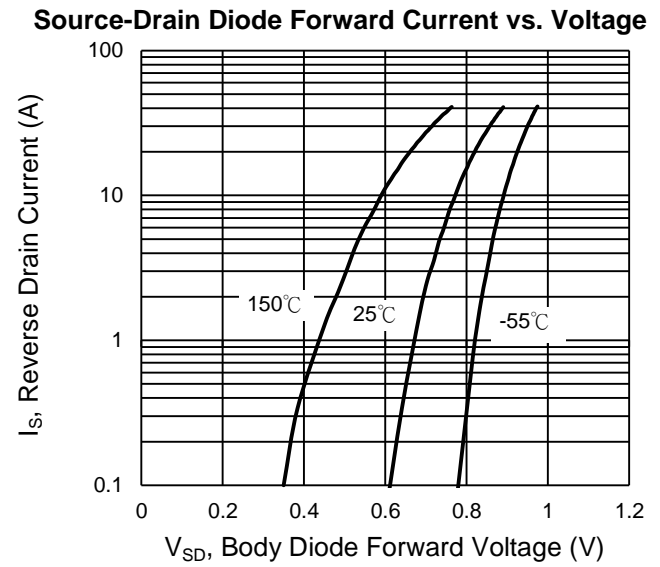
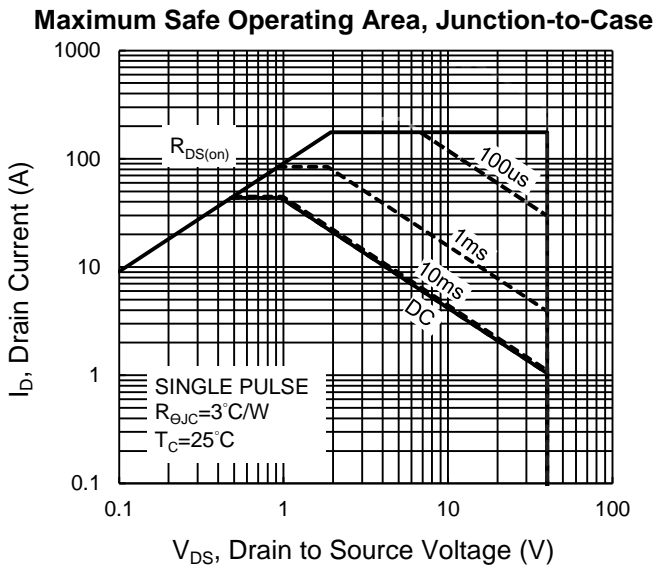
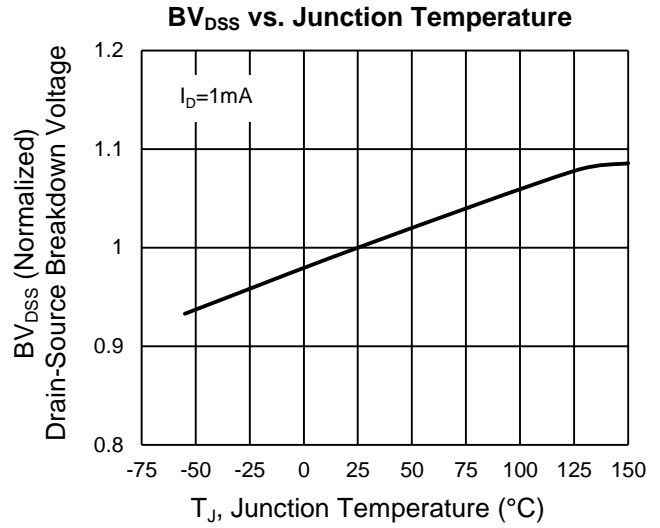
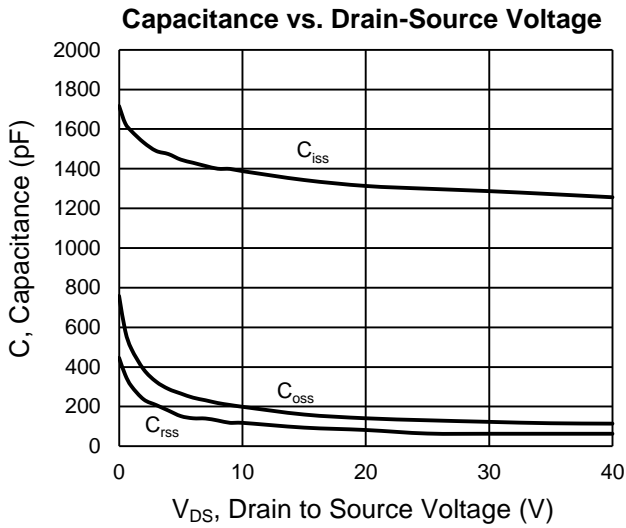


**On-Resistance vs. Gate-Source Voltage**



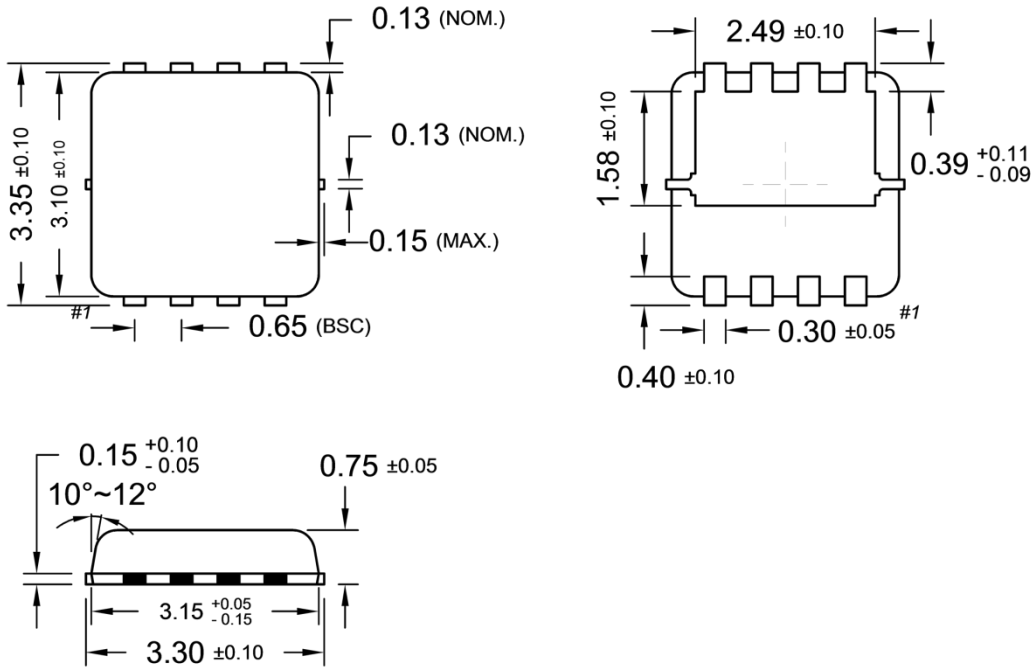
**CHARACTERISTICS CURVES**

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

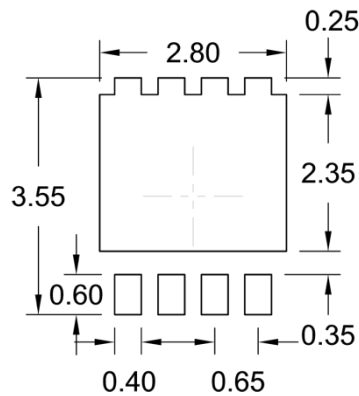


**PACKAGE OUTLINE DIMENSIONS** (Unit: Millimeters)

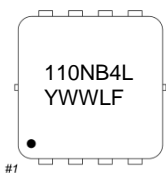
**PDFN33**



**SUGGESTED PAD LAYOUT** (Unit: Millimeters)



**MARKING DIAGRAM**



- Y** = Year Code
- WW** = Week Code (01~52)
- L** = Lot Code (1~9,A~Z)
- F** = Factory Code

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